

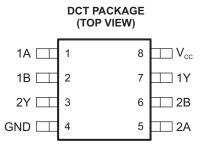
SCES547D - FEBRUARY 2004 - REVISED DECEMBER 2013

Dual 2-Input NAND Gate With Schmitt-Trigger Inputs

Check for Samples: SN74LVC2G132

FEATURES

- Available in Texas Instruments NanoFree™ Package
- Supports 5-V V_{CC} Operation
- Inputs Accept Voltages to 5.5 V •
- Max t_{pd} of 5.3 ns at 3.3 V
- Low Power Consumption, 10-µA Max I_{CC}
- ±24-mA Output Drive at 3.3 V
- Typical V_{OLP} (Output Ground Bounce) <0.8 V at $V_{CC} = 3.3 V, T_A = 25^{\circ}C$
- Typical V_{OHV} (Output V_{OH} Undershoot) >2 V at $V_{CC} = 3.3 V, T_A = 25^{\circ}C$
- Ioff Supports Live Insertion, Partial Power **Down Mode, and Back Drive Protection**
- Support Translation Down (5V to 3.3V and 3.3V to 1.8V)
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Protection Exceeds JESD 22
 - 2000-V Human-Body Model (A114-A)
 - 200-V Machine Model (A115-A)
 - 1000-V Charged-Device Model (C101)



See mechanical drawings for dimensions.

DESCRIPTION

This dual 2-input NAND gate with Schmitt-trigger inputs is designed for 1.65-V to 5.5-V V_{CC} operation.

The SN74LVC2G132 contains two inverters and performs the Boolean function $Y = \overline{A \cdot B}$ or $Y = \overline{A} + \overline{B}$ in positive logic. The device functions as two independent inverters, but because of Schmitt action, it has different input threshold levels for positive-going $(V_{T_{+}})$ and negative-going $(V_{T_{-}})$ signals.

NanoFree™ package technology is a major breakthrough in IC packaging concepts, using the die as the package.

This device can be triggered from the slowest of input ramps and still give clean jitter-free output signals.

This device is fully specified for partial-power-down applications using Ioff. The Ioff circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

I		VIEW)	=
1AⅢ	1	8	$\Box V_{cc}$
1B 🗔	2	7	∐ 1Y
2Y 🗔	3	6	<u> </u>
GND 🖂	4	5	2A

(BO1	PACKA TOM V	IEW)
GND	O4 5O	2A
2Y	0360	2B

2Y	O360	2B
1B	0270	1Y
1A	0180	V _{cc}

AA.

Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet. NanoFree is a trademark of Texas Instruments.

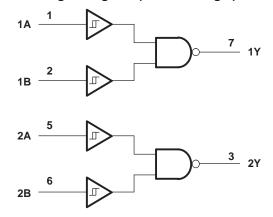


SCES547D-FEBRUARY 2004-REVISED DECEMBER 2013

These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

F	unction (Each G	
INP	UTS	OUTPUT
Α	В	Y
L	L	Н
L	Н	н
Н	L	н
Н	Н	L

Logic Diagram (Positive Logic)



Absolute Maximum Ratings⁽¹⁾

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V_{CC}	Supply voltage range		-0.5	6.5	V
VI	Input voltage range ⁽²⁾		-0.5	6.5	V
Vo	Voltage range applied to any output in the hi	igh-impedance or power-off state ⁽²⁾	-0.5	6.5	V
Vo	Voltage range applied to any output in the hi	igh or low state ^{(2) (3)}	-0.5	V _{CC} + 0.5	V
I _{IK}	Input clamp current	V ₁ < 0		-50	mA
I _{OK}	Output clamp current	V _O < 0		-50	mA
I _O	Continuous output current			±50	mA
	Continuous current through V_{CC} or GND			±100	mA
		DCT package		220	
θ_{JA}	Package thermal impedance ⁽⁴⁾	DCU package		227	°C/W
		YZP package		102	
T _{stg}	Storage temperature range		-65	150	°C

(1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) The input and output negative-voltage ratings may be exceeded if the input and output current ratings are observed.

(3) The value of V_{CC} is provided in the recommended operating conditions table.

(4) The package thermal impedance is calculated in accordance with JESD 51-7



SCES547D - FEBRUARY 2004 - REVISED DECEMBER 2013

Recommended Operating Conditions⁽¹⁾

			MIN	MAX	UNIT
V	Supply voltage	Operating	1.65	5.5	V
V _{CC}	Supply voltage	Data retention only	1.5		v
VI	Input voltage		0	5.5	V
Vo	Output voltage		0	V _{CC}	V
		V _{CC} = 1.65 V		-4	
		V _{CC} = 2.3 V		-8	
I _{OH}	High-level output current	N 0.1		-16	mA
		V _{CC} = 3 V		-24	
		V _{CC} = 4.5 V		-32	
		V _{CC} = 1.65 V		4	
		V _{CC} = 2.3 V		8	
I _{OL}	Low-level output current	N 0.1		16	mA
	$V_{CC} = 3 V$ $V_{CC} = 4.5 V$			24	
				32	
T _A	Operating free-air temperature		-40	125	°C

(1) All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.



Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	v	-40°	°C to 85°C	–40°C to 125°C			
PARAMETER	TEST CONDITIONS	V _{cc}	MIN	TYP ⁽¹⁾ MAX	MIN	TYP ⁽¹⁾ MAX	Т	
		1.65 V	0.79	1.16	0.79	1.16		
V _{T+}		2.3 V	1.11	1.56	1.11	1.56	1	
Positive-going		3 V	1.5	1.87	1.5	1.87	V	
input threshold voltage		4.5 V	2.16	2.74	2.16	2.74	1	
		5.5 V	2.61	3.33	2.61	3.33	1	
		1.65 V	0.39	0.62	0.39	0.62		
V _{T-}		2.3 V	0.58	0.87	0.58	0.87	1	
Negative-going		3 V	0.84	1.14	0.84	1.14	V	
input threshold voltage		4.5 V	1.41	1.79	1.41	1.79	Ī	
		5.5 V	1.87	2.29	1.87	2.29	1	
		1.65 V	0.37	0.62	0.37	0.62		
ΔV_{T}		2.3 V	0.48	0.77	0.48	0.77		
Hysteresis		3 V	0.56	0.87	0.56	0.87	V	
$(V_{T+} - V_{T-})$		4.5 V	0.71	1.04	0.71	1.04		
		5.5 V	0.71	1.11	0.71	1.11	1	
	I _{OH} = -100 μA	1.65 V to 5.5 V	V _{CC} - 0.1		V _{CC} - 0.1			
	$I_{OH} = -4 \text{ mA}$	1.65 V	1.2		1.2		1	
	$I_{OH} = -8 \text{ mA}$	2.3 V	1.9		1.9			
V _{OH}	I _{OH} = -16 mA		2.4		2.4			
	I _{OH} = -24 mA	3 V	2.3		2.3		Ī	
	I _{OH} = -32 mA	4.5 V	3.8		3.8		1	
	I _{OL} = 100 μA	1.65 V to 5.5 V		0.1		0.1		
	I _{OL} = 4 mA	1.65 V		0.45		0.45	1	
	I _{OL} = 8 mA	2.3 V		0.3		0.3	Ι.,	
V _{OL}	I _{OL} = 16 mA	<u> </u>		0.4		0.4	V	
	I _{OL} = 24 mA	3 V		0.55		0.65	1	
	I _{OL} = 32 mA	4.5 V		0.55		0.65	Ī	
II A or B inputs	V _I = 5.5 V or GND	1.65 V to 5.5 V		±1		±1	μA	
l _{off}	$V_1 \text{ or } V_0 = 5.5 \text{ V}$	0		±10		±10	μA	
	$V_{I} = V_{CC}$ or GND, $I_{O} = 0$	1.65 V to 5.5 V		10		10	μA	
ΔI _{CC}	One input at $V_{CC} = 0.6 V$, Other inputs at V_{CC} or GND	3 V to 5.5 V		500		500	μA	
CI	$V_I = V_{CC}$ or GND	3.3 V		3.5			pF	

(1) All typical values are at V_{CC} = 3.3 V, T_A = 25°C.



SCES547D-FEBRUARY 2004-REVISED DECEMBER 2013

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Switching Characteristics

over recommended operating free-air temperature range, $C_L = 15 \text{ pF}$ (unless otherwise noted) (see Figure 1)

	гран та			SN74LVC2G132 -40°C to 85°C							
PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CC} = ± 0.1		V _{CC} = ± 0.2		V _{CC} = ± 0.3		V _{CC} = ± 0.5		UNIT
			MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
t _{pd}	A or B	Y	4	16	2.5	7	2	5.3	1.5	4.4	ns

Switching Characteristics

over recommended operating free-air temperature range, $C_L = 30 \text{ pF}$ or 50 pF (unless otherwise noted) (see Figure 2)

						SN74LV -40°C t	C2G132 o 85°C				
PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CC} = ± 0.1		V _{CC} = ± 0.2		V _{CC} = ± 0.3		V _{CC} = ± 0.5		UNIT
			MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
t _{pd}	A or B	Y	4	16	3	7.5	2	6	2	5	ns

Switching Characteristics

over recommended operating free-air temperature range, C_L = 30 pF or 50 pF (unless otherwise noted) (see Figure 2)

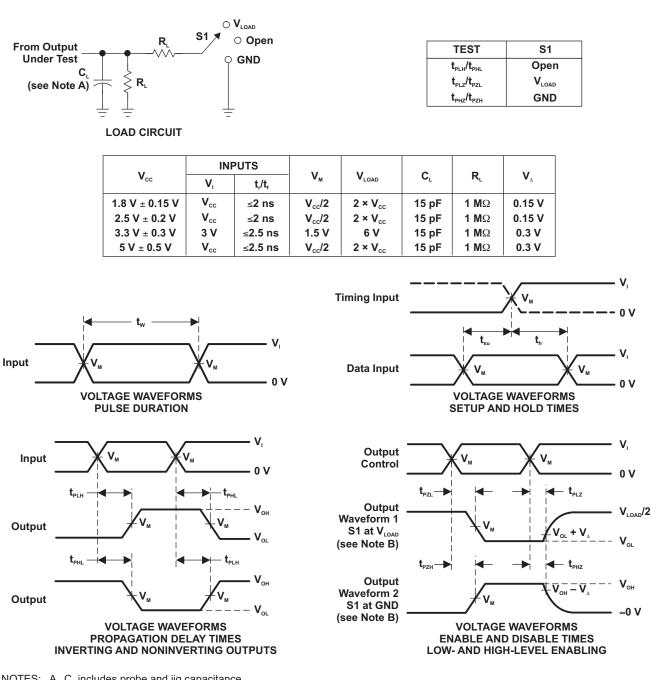
							C2G132 o 125°C				
PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CC} = ± 0.1		V _{CC} = ± 0.		V _{CC} = ± 0.3		V _{CC} = ± 0.5		UNIT
			MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
t _{pd}	A or B	Y	4	17	3	8.5	2	7	2	6	ns

Operating Characteristics

 $T_A = 25^{\circ}C$

	PARAMETER	TEST	V _{CC} = 1.8 V	V _{CC} = 2.5 V	V _{CC} = 3.3 V	$V_{CC} = 5 V$	UNIT
	FARAMETER	CONDITIONS	ТҮР	TYP	ТҮР	ТҮР	UNIT
C_{pd}	Power dissipation capacitance	f = 10 MHz	17	18	18	20	pF

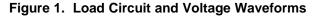
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Parameter Measurement Information

NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control. C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, Z₀ = 50 Ω .
- D. The outputs are measured one at a time, with one transition per measurement.
- E. t_{PLZ} and t_{PHZ} are the same as t_{dis} .
- F. t_{PZL} and t_{PZH} are the same as t_{en} .
- G. $t_{\mbox{\tiny PLH}}$ and $t_{\mbox{\tiny PHL}}$ are the same as $t_{\mbox{\tiny pd}}$
- H. All parameters and waveforms are not applicable to all devices.



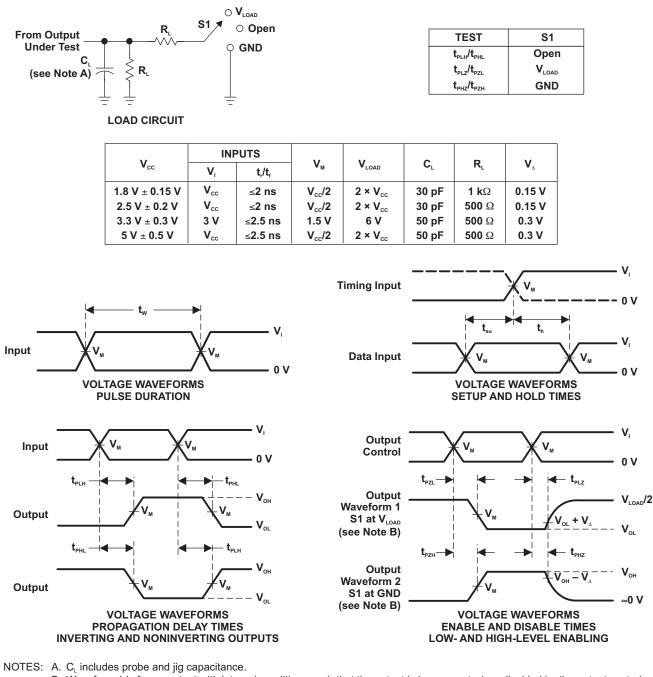


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Parameter Measurement Information



B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control. C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, Z₀ = 50 Ω .

- D. The outputs are measured one at a time, with one transition per measurement.
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- G. $t_{\mbox{\tiny PLH}}$ and $t_{\mbox{\tiny PHL}}$ are the same as $t_{\mbox{\tiny pd}}$
- H. All parameters and waveforms are not applicable to all devices.

Figure 2. Load Circuit and Voltage Waveforms

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REVISION HISTORY

Changes from Revision C (January 2007) to Revision D Upd Ren Add Upo

8

Texas NSTRUMENTS

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Page

1

1 2

3

dated document to new TI data sheet format.
noved Ordering Information table.
ded ESD warning
dated operating temperature range



PACKAGING INFORMATION

Orderable part number	Status (1)	Material type	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material	MSL rating/ Peak reflow	Op temp (°C)	Part marking
	(1)	(2)			(0)	(4)	(5)		(0)
74LVC2G132DCTRG4	Active	Production	SSOP (DCT) 8	3000 LARGE T&R	Yes	NIPDAU NIPDAU	Level-1-260C-UNLIM	-40 to 125	C3B (R, Z)
74LVC2G132DCTRG4.Z	Active	Production	SSOP (DCT) 8	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	C3B (R, Z)
74LVC2G132DCURG4	Active	Production	VSSOP (DCU) 8	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	C3BR
74LVC2G132DCURG4.Z	Active	Production	VSSOP (DCU) 8	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	C3BR
74LVC2G132DCUTG4	Active	Production	VSSOP (DCU) 8	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-	C3BR
74LVC2G132DCUTG4.Z	Active	Production	VSSOP (DCU) 8	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	C3BR
SN74LVC2G132DCTR	Active	Production	SSOP (DCT) 8	3000 LARGE T&R	Yes	NIPDAU SN NIPDAU	Level-1-260C-UNLIM	-40 to 125	(2WM5, C3B) (R, Z)
SN74LVC2G132DCTR.Z	Active	Production	SSOP (DCT) 8	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	(2WM5, C3B) (R, Z)
SN74LVC2G132DCUR	Active	Production	VSSOP (DCU) 8	3000 LARGE T&R	Yes	NIPDAU SN	Level-1-260C-UNLIM	-40 to 125	(3B, C3BJ, C3BR) CZ
SN74LVC2G132DCUR.Z	Active	Production	VSSOP (DCU) 8	3000 LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	(3B, C3BJ, C3BR) CZ
SN74LVC2G132DCUT	Active	Production	VSSOP (DCU) 8	250 SMALL T&R	Yes	NIPDAU SN	Level-1-260C-UNLIM	-40 to 125	(C3BJ, C3BR)
SN74LVC2G132DCUT.Z	Active	Production	VSSOP (DCU) 8	250 SMALL T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	(C3BJ, C3BR)
SN74LVC2G132DCUTG4.Z	Active	Production	VSSOP (DCU) 8	250 SMALL T&R	-	Call TI	Call TI	-40 to 125	
SN74LVC2G132YZPR	Active	Production	DSBGA (YZP) 8	3000 LARGE T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 85	(D57, D5N)
SN74LVC2G132YZPR.Z	Active	Production	DSBGA (YZP) 8	3000 LARGE T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 125	(D57, D5N)

⁽¹⁾ **Status:** For more details on status, see our product life cycle.

⁽²⁾ **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

(4) Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.



PACKAGE OPTION ADDENDUM

⁽⁵⁾ MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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Texas

STRUMENTS

TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal												
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
74LVC2G132DCTRG4	SSOP	DCT	8	3000	177.8	12.4	3.45	4.4	1.45	4.0	12.0	Q3
74LVC2G132DCURG4	VSSOP	DCU	8	3000	180.0	8.4	2.25	3.35	1.05	4.0	8.0	Q3
74LVC2G132DCUTG4	VSSOP	DCU	8	250	180.0	8.4	2.25	3.35	1.05	4.0	8.0	Q3
SN74LVC2G132DCTR	SSOP	DCT	8	3000	180.0	12.4	3.15	4.35	1.55	4.0	12.0	Q3
SN74LVC2G132DCUR	VSSOP	DCU	8	3000	178.0	9.0	2.25	3.35	1.05	4.0	8.0	Q3
SN74LVC2G132DCUT	VSSOP	DCU	8	250	178.0	9.0	2.25	3.35	1.05	4.0	8.0	Q3
SN74LVC2G132YZPR	DSBGA	YZP	8	3000	178.0	9.2	1.02	2.02	0.63	4.0	8.0	Q1



PACKAGE MATERIALS INFORMATION

8-Oct-2024



		·					
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
74LVC2G132DCTRG4	SSOP	DCT	8	3000	183.0	183.0	20.0
74LVC2G132DCURG4	VSSOP	DCU	8	3000	202.0	201.0	28.0
74LVC2G132DCUTG4	VSSOP	DCU	8	250	202.0	201.0	28.0
SN74LVC2G132DCTR	SSOP	DCT	8	3000	190.0	190.0	30.0
SN74LVC2G132DCUR	VSSOP	DCU	8	3000	180.0	180.0	18.0
SN74LVC2G132DCUT	VSSOP	DCU	8	250	180.0	180.0	18.0
SN74LVC2G132YZPR	DSBGA	YZP	8	3000	220.0	220.0	35.0

YZP0008



PACKAGE OUTLINE

DSBGA - 0.5 mm max height

DIE SIZE BALL GRID ARRAY



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.



YZP0008

EXAMPLE BOARD LAYOUT

DSBGA - 0.5 mm max height

DIE SIZE BALL GRID ARRAY



NOTES: (continued)

3. Final dimensions may vary due to manufacturing tolerance considerations and also routing constraints. For more information, see Texas Instruments literature number SNVA009 (www.ti.com/lit/snva009).



YZP0008

EXAMPLE STENCIL DESIGN

DSBGA - 0.5 mm max height

DIE SIZE BALL GRID ARRAY



NOTES: (continued)

4. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release.



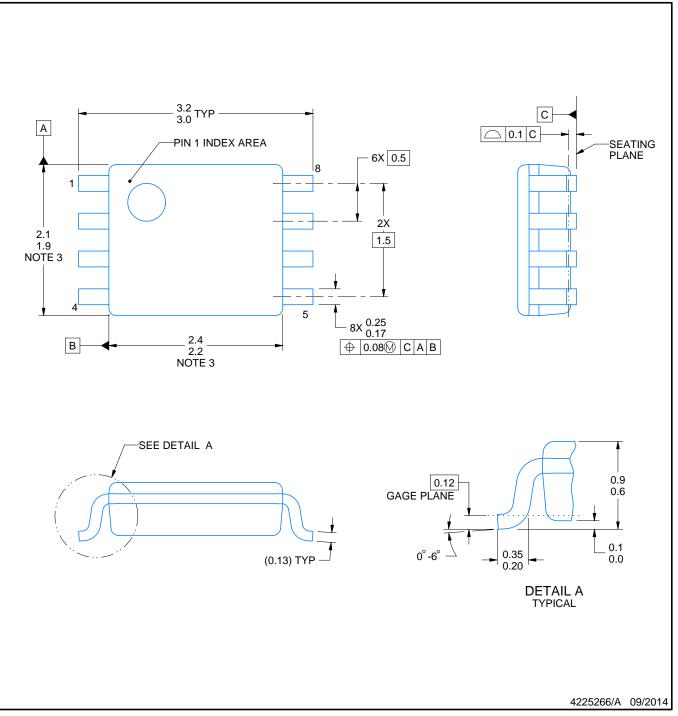
DCU0008A



PACKAGE OUTLINE

VSSOP - 0.9 mm max height

SMALL OUTLINE PACKAGE



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice. 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side. 4. Reference JEDEC registration MO-187 variation CA.



DCU0008A

EXAMPLE BOARD LAYOUT

VSSOP - 0.9 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

5. Publication IPC-7351 may have alternate designs.

6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



DCU0008A

EXAMPLE STENCIL DESIGN

VSSOP - 0.9 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

8. Board assembly site may have different recommendations for stencil design.



^{7.} Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

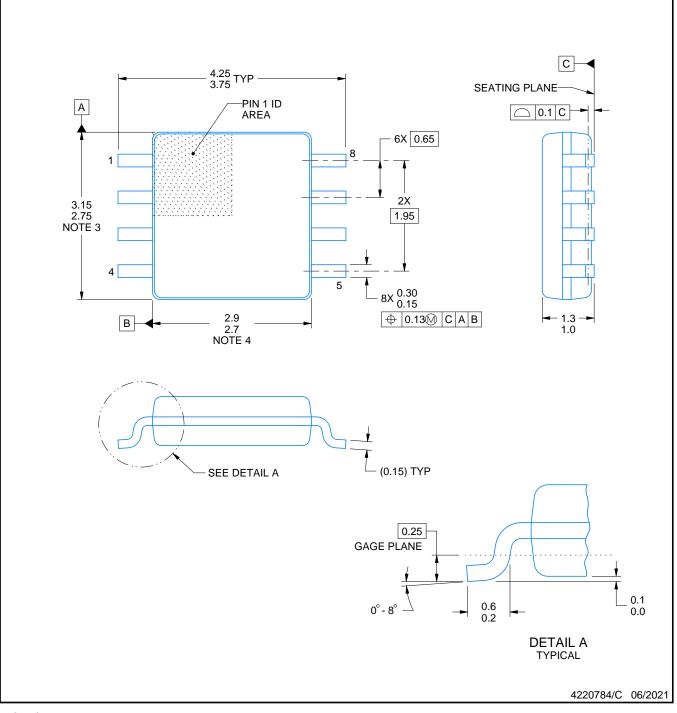
DCT0008A



PACKAGE OUTLINE

SSOP - 1.3 mm max height

SMALL OUTLINE PACKAGE



NOTES:

- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice. 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.

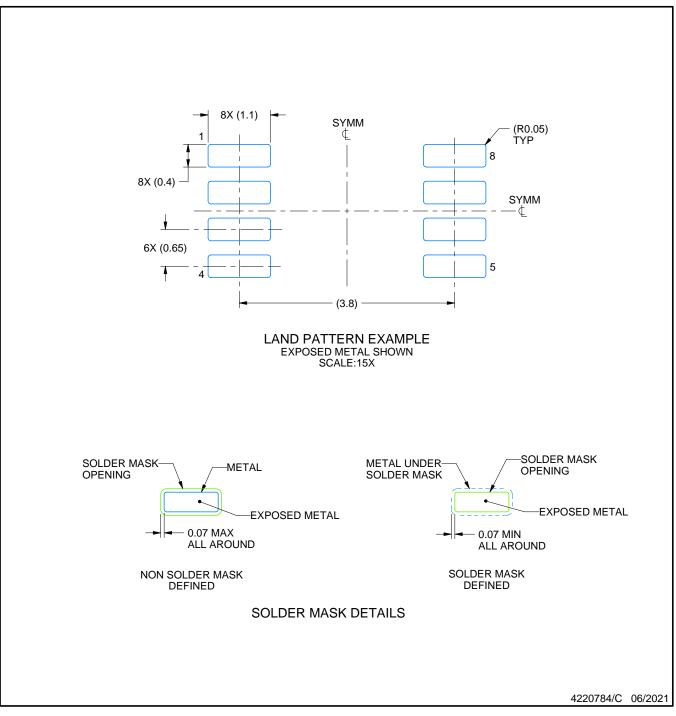


DCT0008A

EXAMPLE BOARD LAYOUT

SSOP - 1.3 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

Publication IPC-7351 may have alternate designs.
 Solder mask tolerances between and around signal pads can vary based on board fabrication site.



DCT0008A

EXAMPLE STENCIL DESIGN

SSOP - 1.3 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

8. Board assembly site may have different recommendations for stencil design.



^{7.} Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

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